



molecules necessarily possess the symmetry  $m=C_s$ . The bond lengths and angles, together with their estimated standard deviations, are given in Table 3. The accuracy

Table 3. *Bond lengths and angles*

Se-C	1.86 Å	with $\sigma=0.10$ Å
C-N	1.42 Å	with $\sigma=0.15$ Å
Se-C-N	177°	with $\sigma=6^\circ$
C-Se-C	119°	with $\sigma=6^\circ$

of these values is so low that no conclusions about the nature of the bonding can be drawn. The closest approach between neighbouring molecules is between selenium and nitrogen atoms (close approaches shown by dotted lines in Fig. 1); the distance between these is 2.35 Å, with standard deviation 0.10 Å, which is significantly shorter than the sum of the van der Waals radii (3.5 Å).

The calculations were carried out on the Durham University Pegasus Computer with programs devised by Cruickshank & Pilling (1961) and Samet. The atomic scattering factors used were those of Thomas & Umeda

(1957) for selenium, and Berghuis, Haanappel, Potters, Loopstra, MacGillavry & Veenendaal (1955) for carbon and nitrogen.

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### Electron-diffraction evidence of an outward growth tendency in electrolytic crystal growth.

By A. K. N. REDDY\* and H. WILMAN, *Applied Physical Chemistry of Surfaces Laboratory, Chemical Engineering Department, Imperial College, London, England*

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The present authors have systematically studied, by electron diffraction, the structure and growth of iron electrodeposits on copper (100), (110) and (111) single-crystal substrates. The work has been described in detail elsewhere (Reddy, 1958; Reddy & Wilman, 1959). The purpose of this short communication is to describe an interesting observation made on iron electrodeposits on the copper (110) face.

#### Results

The epitaxy of iron on the copper (110) face corresponded to Fe (211) || Cu (110) with Fe  $[\bar{1}11]$  || Cu  $[1\bar{1}0]$ . This orientation relationship only stipulates that two crystal axes of iron are fixed relative to the copper substrate lattice. The third axis can take up one of two possible positions. Thus the iron deposit crystals can grow on the copper (110) face in two crystallographically equivalent ways without violating the requirements of epitaxy. Corresponding to each of these orientations there is a particular electron diffraction pattern. With the electron beam along the Cu  $[1\bar{1}0]$  azimuth the hexagonal patterns from the two possible orientations coincide with each other. When, however, the beam is along the Cu  $[001]$  azimuth, each orientation contributes a distinct rectangular spot pattern (the sides of the rectangle being in the ratio 1:½) with the 211 spot in the plane of incidence (Figs. 1 and 4).

The interesting feature of patterns with the beam

\* Present address: The Electrochemistry Laboratory, University of Pennsylvania, Philadelphia 4, Pennsylvania, U.S.A.

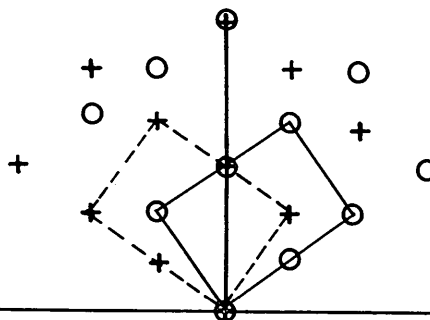


Fig. 4. Theoretical pattern based on Fe (211) || Cu (110) and Fe  $[\bar{1}11]$  || Cu  $[1\bar{1}0]$  with beam parallel to Cu  $[001]$  azimuth.

along the Cu  $[001]$  azimuth concerns the intensity of the component  $\sqrt{2}$ -rectangle patterns. Figs. 1, 2 and 3, for example, are patterns obtained from 1000 Å thick iron deposits from a ferrous ammonium sulphate (350 g.l<sup>-1</sup>)—sulphuric acid (2.5 g.l<sup>-1</sup>) bath with a current density of 25 mA.cm<sup>-2</sup> at room temperature (20 °C). They show that the two component patterns are equal in intensity only in Fig. 1, which has been taken with the electron beam grazing the flat middle part of the single-crystal surface. At the curved edges of the specimen, where the surface deviates slightly from the Cu (110) plane, Figs. 2 and 3 show that one of the component patterns is much more intense than the other. That component pattern is more intense in which the line joining the 000 and 011 spots makes a smaller angle